VS-30TPS16PbF, VS-30TPS16-M3

Vishay Semiconductors

Thyristor High Voltage, Phase Control SCR, 30 A





TO-247AC

2 (A)	
*	٦
1 (K)	(G) 3

PRODUCT SUMMARY	
Package	TO-247AC
Diode variation	Single SCR
I _{T(AV)}	20 A
V _{DRM} /V _{RRM}	1600 V
V _{TM}	1.3 V
I _{GT}	45 mA
T _J	- 40 °C to 125 °C

FEATURES

- High voltage (up to 1600 V)
- Designed and qualified according JEDEC-JESD47



• Material categorization: For definitions of compliance please see www.vishay.com/doc?99912





RoHS **HALOGEN FREE**

APPLICATIONS

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

DESCRIPTION

The VS-30TPS16... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

MAJOR RATINGS	AND CHARACTERISTICS		
PARAMETER	TEST CONDITIONS	VALUES	UNITS
I _{T(AV)}	Sinusoidal waveform	20	^
I _{RMS}		30	Α Α
V _{RRM} /V _{DRM}		1600	V
I _{TSM}		300	А
V _T	20 A, T _J = 25 °C	1.3	V
dV/dt		500	V/µs
dl/dt		150	A/µs
T _J		- 40 to 125	°C

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA
VS-30TPS16PbF, VS-30TPS16-M3	1600	1700	10



VS-30TPS16PbF, VS-30TPS16-M3

Vishay Semiconductors

ABSOLUTE MAXIMUM RATING	S				
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 95 °C, 180° conduction	half sine wave	20	
Maximum RMS on-state current	I _{RMS}			30	^
Maximum peak, one-cycle,	_	10 ms sine pulse, rated V _{RRM}	applied	250	Α
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage	reapplied	300	
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM}	applied	310	A2-
Maximum 1-t for fusing	1-1	10 ms sine pulse, no voltage reapplied		442	A ² s
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage re	eapplied	4420	A²√s
Maximum on-state voltage drop	V_{TM}	20 A, T _J = 25 °C		1.3	V
On-state slope resistance	r _t	T 105.00		12	mΩ
Threshold voltage	V _{T(TO)}	T _J = 125 °C		1.0	V
Maximum rayana and divast lackage august	1 //	T _J = 25 °C	V Detect V A/	0.5	
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	V _R = Rated V _{RRM} /V _{DRM}	10	
Maximum holding current	I _H	Anode supply = 6 V, resistive	load, initial I _T = 1 A, T _J = 25 °C	150	mA
Maximum latching current	ΙL	Anode supply = 6 V, resistive	load, T _J = 25 °C	200	
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to 80	0 % V _{DRM} , R _g -k = Open	500	V/µs
Maximum rate of rise of turned-on current	dI/dt			150	A/μs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P_{GM}		8.0	W
Maximum average gate power	P _{G(AV)}		2.0	VV
Maximum peak positive gate current	+ I _{GM}		1.5	Α
Maximum peak negative gate voltage	- V _{GM}		10	V
		Anode supply = 6 V, resistive load, T _J = - 10 °C	60	
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T_J = 25 $^{\circ}$ C	45	mA
		Anode supply = 6 V, resistive load, T _J = 125 °C	20	
		Anode supply = 6 V, resistive load, T _J = - 10 °C	2.5	
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	V
voltage to trigger		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V
Maximum DC gate voltage not to trigger	V_{GD}	T = 105 °C V = Peted value	0.25	
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = Rated value	2.0	mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T _{.I} = 125 °C	4	μs
Typical turn-off time	tq	IJ= 125 C	110	



THERMAL AND MECH	IANICAL	SPECIFIC	ATIONS		
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		- 40 to 125	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	0.8	
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation 40	°C/W	
Maximum thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased		
Approximate weight				6	g
Approximate weight				0.21	OZ.
Mounting torque	minimum			6 (5)	kgf · cm
woulding torque	maximum			12 (10)	(lbf · in)
Marking device			Case style TO-247AC (JEDEC)	30TF	PS16

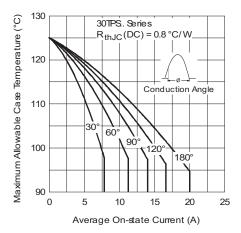


Fig. 1 - Current Rating Characteristics

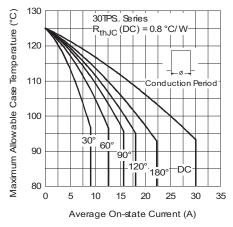


Fig. 2 - Current Rating Characteristics

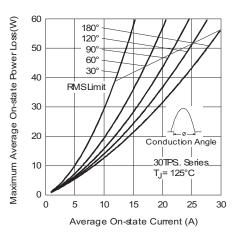


Fig. 3 - On-State Power Loss Characteristics

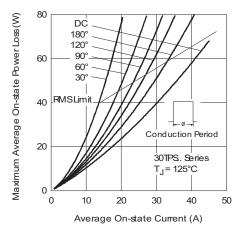


Fig. 4 - On-State Power Loss Characteristics

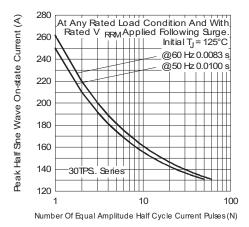


Fig. 5 - Maximum Non-Repetitive Surge Current

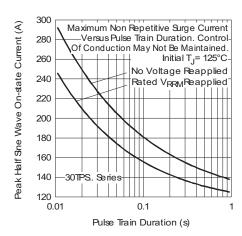


Fig. 6 - Maximum Non-Repetitive Surge Current

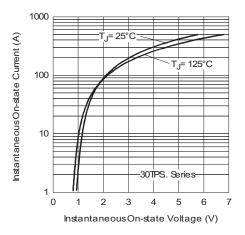


Fig. 7 - On-State Voltage Drop Characteristics

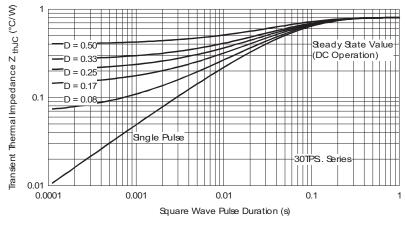


Fig. 8 - Thermal Impedance ZthJC Characteristics

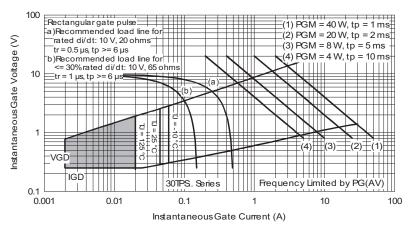
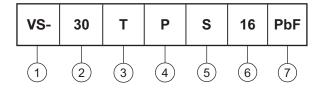


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Current rating (30 = 30 A)

3 - Circuit configuration:

T = Thyristor

4 - Package:

P = TO-247

5 - Type of silicon:

S = Standard recovery rectifier

6 - Voltage rating (16 = 1600 V)

7 - Environmental digit:

PbF = Lead (Pb)-free and RoHS compliant

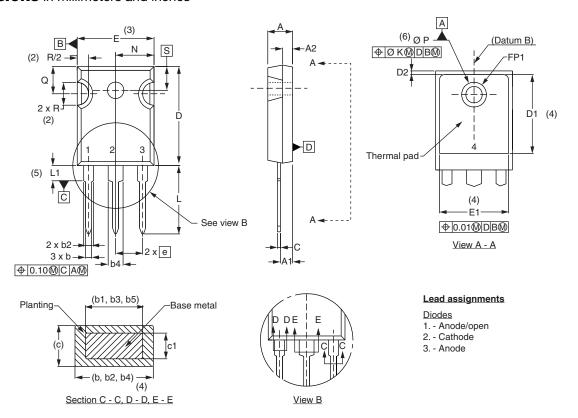
-M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

ORDERING INFORMATI	ON (Example)		
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-30TPS16PbF	25	500	Antistatic plastic tubes
VS-30TPS16-M3	25	500	Antistatic plastic tubes

	LINKS TO RELAT	ED DOCUMENTS
Dimensions		www.vishay.com/doc?95223
Dort marking information	TO-247AC PbF	www.vishay.com/doc?95226
Part marking information	TO-247AC -M3	www.vishay.com/doc?95007



DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	S INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.37	0.065	0.094	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.86	0.015	0.034	
c1	0.38	0.76	0.015	0.030	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.72	-	0.540	-	
е	5.46 BSC		0.215 BSC		
FK	2.54		0.010		
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62 BSC		0.3		
ΦР	3.56	3.66	0.14	0.144	
ФР1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	1.78	0.216	
S	5.51 BSC		0.217 BSC		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000